SCBS680A - MARCH 1997 - REVISED MAY 1997

- Outputs Have Equivalent 25-Ω Series Resistors, So No External Resistors Are Required
- State-of-the-Art *EPIC-*II*B*<sup>™</sup> BiCMOS Design Significantly Reduces Power Dissipation
- High-Impedance State During Power Up and Power Down
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- ESD Protection Exceeds 2000 V Per MIL-STD-833, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 1 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Thin Very Small-Outline (DGV) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

#### description

These octal transceivers and line drivers are designed for asynchronous communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable  $(\overline{OE})$  input can be used to disable the device so the buses are effectively isolated.

SN54ABTR2245 . . . J PACKAGE SN74ABTR2245 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)

	(	,	
DIR		J <sub>20</sub>	] <u>∨c</u> c
A1	2	19	] OE
A2	3	18	] B1
A3	4	17	B2
A4		16	] B3
A5		15	] B4
A6	7	14	] B5
A7	8	13	] B6
A8	9	12	B7
GND	10	11	] B8

SN54ABTR2245 . . . FK PACKAGE (TOP VIEW)

	A2 DIR OE	
1		
A3	4 18	B1
A4	5 17	B2
A3 A4 A5 A6 A7	6 16	B3
A6		Β4
A7	8 14	B5
	9 10 11 12 13	
1	GND B8 B8 B6 B6	

Both the A-port and B-port outputs, which are designed to sink up to 12 mA, include equivalent  $25 \cdot \Omega$  series resistors to reduce overshoot and undershoot.

When  $V_{CC}$  is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABTR2245 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABTR2245 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE										
INP	UTS	OPERATION								
OE	DIR	OPERATION								
L	L	B data to A bus								
L	Н	A data to B bus								
Н	Х	Isolation								



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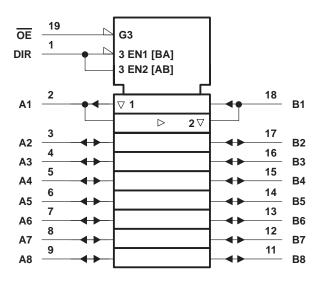
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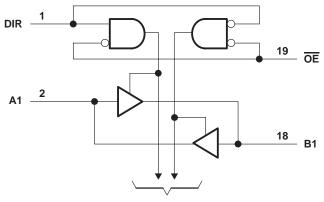
SCBS680A - MARCH 1997 - REVISED MAY 1997

### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

# logic diagram (positive logic)

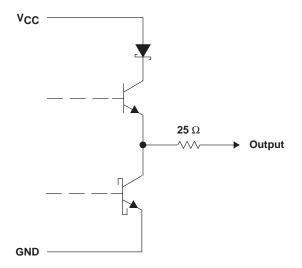


**To Seven Other Channels** 



SCBS680A - MARCH 1997 - REVISED MAY 1997

#### output schematic



All resistor values shown are nominal.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>		
Input voltage range, V <sub>I</sub> (except I/O ports) (see		
Voltage range applied to any output in the high	n or power-off state, V <sub>O</sub>	
Current into any output in the low state, IO		30 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)		–18 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		–50 mA
Package thermal impedance, $\theta_{JA}$ (see Note 2)	): DB package	115°C/W
	DGV package	146°C/W
	DW package	
	N package	
		128°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.



SCBS680A - MARCH 1997 - REVISED MAY 1997

#### recommended operating conditions (see Note 3)

			SN54ABT	R2245	SN74ABT	R2245	UNIT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2	N	2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0	Vcc	0	VCC	V
ЮН	High-level output current		1	-12		-12	mA
IOL	Low-level output current		n	12		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled	201	5		5	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		<b>Q</b> 200		200		μs/V
Т <sub>А</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.



SCBS680A - MARCH 1997 - REVISED MAY 1997

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CON	IDITIONS	т	A = 25°C	;	SN54AB1	R2245	SN74AB1	R2245	UNIT
PAR	AMEIER	TEST CON	IDITIONS	MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNIT
VIK		V <sub>CC</sub> = 4.5 V,	lj = -18 mA			-1.2		-1.2		-1.2	V
		V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = -1 mA	3.35			3.3		3.35		
Vari	V <sub>CC</sub> = 5 V,		I <sub>OH</sub> = -1 mA	3.85			3.8		3.85		V
VOH		V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = -3 mA				3		3.1		v
		VCC = 4.5 V	I <sub>OH</sub> = -12 mA	2.6					2.6		
VOL		V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 8 mA			0.65		0.8		0.65	V
VOL		VCC = 4.5 V	I <sub>OL</sub> = 12 mA			0.8				0.8	v
V <sub>hys</sub>					100						mV
1.	Control inputs	$V_{CC} = 0$ to 5.5 V, V <sub>I</sub>	= V <sub>CC</sub> or GND			±1		±1		±1	
11	A or B ports	$V_{CC} = 2.1 V \text{ to } 5.5 V_{I} = V_{CC} \text{ or GND}$	Ι,			±20		±20		±20	μA
IOZH‡		$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 5.5 \text{ V}, \text{ V}_{O} = 2.7 \text{ V},$				10		J 10		10	μΑ
I <sub>OZL</sub> ‡		$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 5.5 \text{ V}, \text{ V}_{O} = 0.5 \text{ V},$				-10	07 <sub>0</sub>	-10		-10	μΑ
IOZPU	}	$\frac{V_{CC}}{OE} = 0$ to 2.1 V, $V_{O} = 0.5$ V to 2.7 V, OE = X				±50	2000	±50		±50	μΑ
IOZPD	Ì	$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 0, \text{ V}_{CC}$	O = 0.5 V to 2.7 V,			±50	Q	±50		±50	μΑ
loff		V <sub>CC</sub> = 0,	$V_{I} \text{ or } V_{O} \leq 4.5 \text{ V}$			±100				±100	μΑ
ICEX		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 5.5 V	Outputs high			50		50		50	μΑ
۱ <sub>0</sub> ¶		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.5 V	-25		-100	-25	-100	-25	-100	mA
		V <sub>CC</sub> = 5.5 V,	Outputs high		1	250		250		250	μA
ICC	A or B ports	$I_{O} = 0,$	Outputs low		24	32		32		32	mA
		$V_I = V_{CC} \text{ or } GND$	Outputs disabled		0.5	250		250		250	μΑ
	Data inpute	V <sub>CC</sub> = 5.5 V, One input at 3.4 V,	Outputs enabled			1.5		1.5		1.5	
$\Delta I_{CC}^{\#}$	Data inputs Other inputs at		Outputs disabled			0.05		0.05		0.05	mA
	Control inputs	$V_{CC}$ = 5.5 V, One in Other inputs at $V_{CC}$				1.5		1.5		1.5	
Ci		V <sub>I</sub> = 2.5 V or 0.5 V			3						pF
Cio		V <sub>O</sub> = 2.5 V or 0.5 V			6						pF

\* On products compliant to MIL-PRF-38535, this parameter does not apply.

<sup>†</sup> All typical values are at  $V_{CC} = 5 V$ .

<sup>‡</sup> The parameters I<sub>OZH</sub> and I<sub>OZL</sub> include the input leakage current.

§ This parameter is characterized but not production tested.

¶ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

<sup>#</sup>This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.



SCBS680A - MARCH 1997 - REVISED MAY 1997

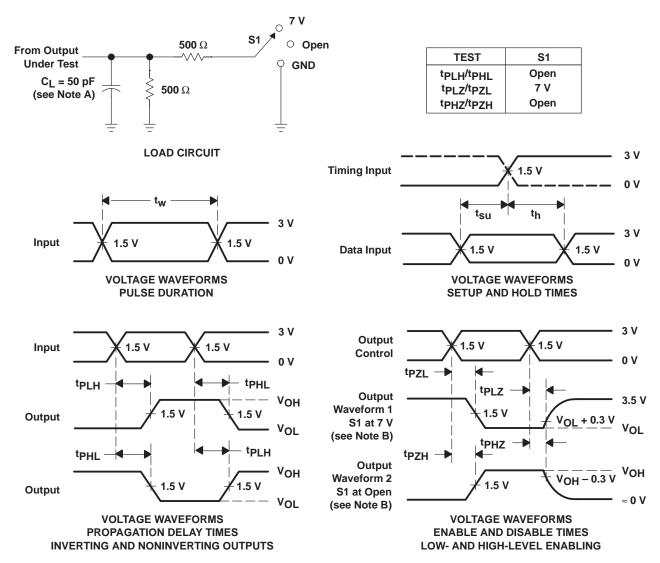
switching characteristics over recommended ranges of supply voltage and operating free-air temperature,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V( Tj	CC = 5 V A = 25°C	3	SN54ABT	R2245	SN74ABT	R2245	UNIT
		(001101)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> PLH	A or B	B or A	1	2.5	3.4	1	4	1	3.8	00
<sup>t</sup> PHL	AUB	BOLA	1	3.2	4.2	1	4.6	1	4.5	ns
<sup>t</sup> PZH	OE	A or B	1.5	3.6	4.9	1.5	6.3	1.5	6.1	50
<sup>t</sup> PZL	OE	AUB	1.5	3.9	5.3	1.5	6.6	1.5	6.3	ns
<sup>t</sup> PHZ	OE	A or P	1.5	3.6	4.7	<b>1</b> .5	5.5	1.5	5.3	
<sup>t</sup> PLZ	UE	A or B	1.5	3.3	4.4	<b>2</b> 1.5	4.9	1.5	4.8	ns

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SCBS680A - MARCH 1997 - REVISED MAY 1997



#### PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABTR2245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ABTR2245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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# PACKAGE MATERIALS INFORMATION

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABTR2245DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ABTR2245PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

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## TUBE



## - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74ABTR2245DW	DW	SOIC	20	25	507	12.83	5080	6.6

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